

FEATURES

- Available as “HR” (high reliability) screened per MIL-PRF-19500, JANTX level. Add “HR” suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding “-PBF” suffix.

MAXIMUM RATINGS

Symbol	Ratings	2N1595	2N1596	2N1597	2N1598	2N1599	Unit
$V_{RSM(REP)}$	Peak reverse blocking voltage*	50	100	200	300	400	V
$I_{T(RMS)}$	Forward current RMS (all conduction angles)	1.6					Amp
I_{TSM}	Peak surge current (one-cycle, 60Hz, $T_J = -65$ to $+125^{\circ}C$)	15					Amp
P_{GM}	Peak gate power – forward	0.1					W
$P_{G(AV)}$	Average gate power – forward	0.01					W
I_{GM}	Peak gate current – forward	0.1					Amp
V_{GFM}	Peak gate voltage – forward	10					V
V_{GRM}	Peak gate voltage – reverse	10					V
T_J	Operating junction temperature range	-65 to $+125$					$^{\circ}C$
T_{STG}	Storage temperature range	-65 to $+150$					$^{\circ}C$

* V_{DRM} or V_{RSM} can be applied for all types on a continuous dc basis without incurring damage.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise specified)

Symbol	Ratings		2N1595	2N1596	2N1597	2N1598	2N1599	Unit
V_{DRM}	Peak forward blocking voltage*	Min.	50	100	200	300	400	V
I_{RRM}	Peak reverse blocking current (Rated V_{DRM} , $T_J = 125^{\circ}C$)	Max.	1.0					mA
I_{DRM}	Peak forward blocking current (Rated V_{DRM} with gate open, $T_J = 125^{\circ}C$)	Max.	1.0					mA
I_{GT}	Gate trigger current Anode voltage = 7.0 Vdc, $R_L = 12\Omega$	Typ. Max.	2.0 10					mA
	Gate trigger voltage	Typ.	0.7					
V_{GT}	Anode voltage = 7.0Vdc, $R_L = 12\Omega$ $V_{DRM} = \text{rated}$, $R_L = 100\Omega$, $T_J = 125^{\circ}C$	Max. Min.	3.0 0.2					V
I_H	Holding current Anode voltage = 7.0 Vdc, gate open	Typ.	5.0					mA
V_{TM}	Forward on-voltage $I_T = 1A$ dc	Typ. Max.	1.1 2.0					V
t_{gt}	Turn-on time ($t_d + t_r$) $I_{GT} = 10mA$, $I_T = 1A$	Typ.	0.8					μs
t_q	Turn-off time $I_T = 1A$, $I_R = 1A$, $dv/dt = 20 V/\mu s$, $T_J = 125^{\circ}C$ $V_{DRM} = \text{rated voltage}$	Typ.	10					μs

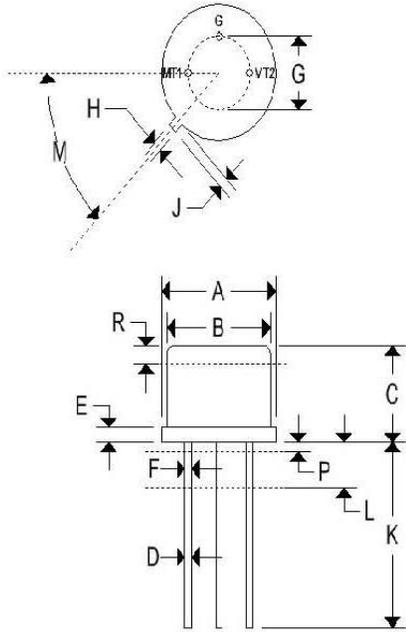
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2N1595-2N1599

SILICON THYRISTORS

MECHANICAL CHARACTERISTICS

Case:	TO-39
Marking:	Body painted, alpha-numeric
Pin out:	See below



	TO-39			
	Inches		Millimeters	
	Min	Max	Min	Max
A	0.335	0.370	8.510	9.390
B	0.305	0.335	7.750	8.500
C	0.240	0.260	6.100	6.600
D	0.016	0.021	0.410	0.530
E	0.009	0.041	0.230	1.040
F	0.016	0.019	0.410	0.480
G	0.200 BSC		5.080 BSC	
H	0.028	0.034	0.720	0.860
J	0.029	0.045	0.740	1.140
K	0.500	0.750	12.700	19.050
L	0.250	-	6.350	-
M	45° BSC		45° BSC	
P	-	0.050	-	1.270
R	0.100	-	2.540	-